



MBRS540T3

The MBRS540T3 employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Pb-Free Package is Available
- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection

Mechanical Characteristics

- Case: Epoxy, Molded, Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 217 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- ESD Rating: Machine Model, C (> 400 V)
Human Body Model, 3B (> 8000 V)
- Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	40	V
Average Rectified Forward Current (At Rated V_R , $T_C = 105^\circ\text{C}$)	$I_{F(AV)}$	5	A
Peak Repetitive Forward Current (At Rated V_R , Square Wave, 20 KHz, $T_C = 80^\circ\text{C}$)	I_{FRM}	10	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	190	A
Storage Temperature Range	Tstg	-65 to +150	°C
Operating Junction Temperature	T_J	-65 to +125	°C
Voltage Rate of Change (Rated V_R)	dv/dt	10,000	V/ μs

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

Preferred Device

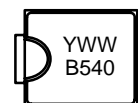
Surface Mount Schottky Power Rectifier

**SCHOTTKY BARRIER
RECTIFIER
5.0 AMPERES
40 VOLTS**

MARKING DIAGRAM



SMC
CASE 403
PLASTIC



B540 = Specific Device Code
Y = Year
W = Work Week

ORDERING INFORMATION

Device	Package	Shipping†
MBRS540T3	SMC	2500/Tape & Reel
MBRS540T3G	SMC (Pb-Free)	2500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance – Junction-to-Lead (Note 1)	$R_{\theta JL}$	12	$^{\circ}C/W$
Thermal Resistance – Junction-to-Ambient (Note 1)	$R_{\theta JA}$	111	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 2)	($i_F = 5.0\text{ A}$, $T_C = 25^{\circ}C$)	V_F	0.50	V
Maximum Instantaneous Reverse Current (Note 2)	(Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 100^{\circ}C$)	i_R	0.3 15	mA

1. Rating applies when surface mounted on the minimum pad size recommended.
2. Pulse Test: Pulse Width $\leq 300\ \mu s$, Duty Cycle $\leq 2.0\%$.

TYPICAL CHARACTERISTICS

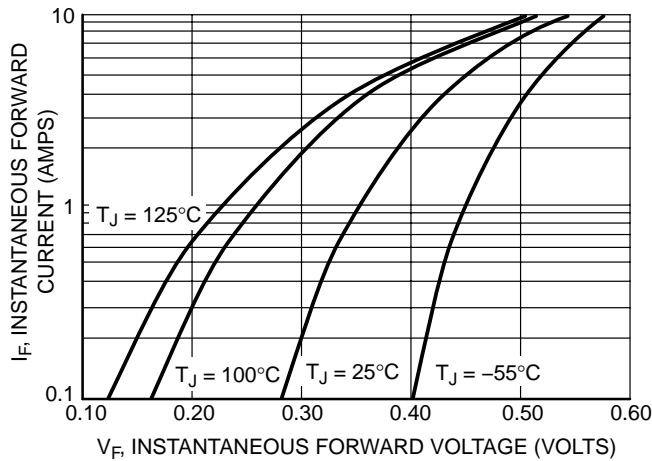


Figure 1. Typical Forward Voltage

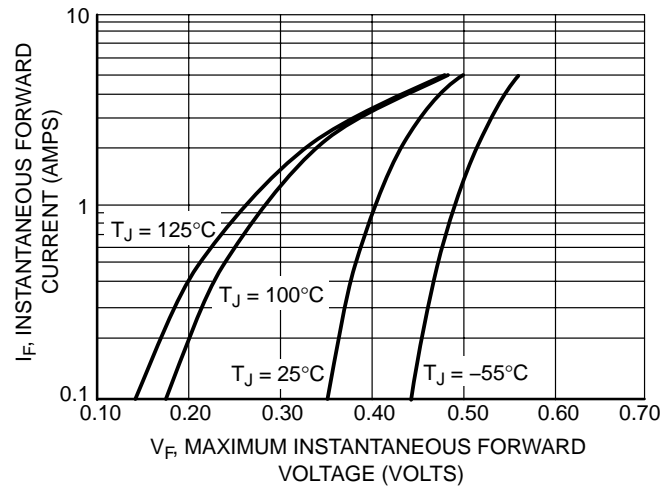


Figure 2. Maximum Forward Voltage

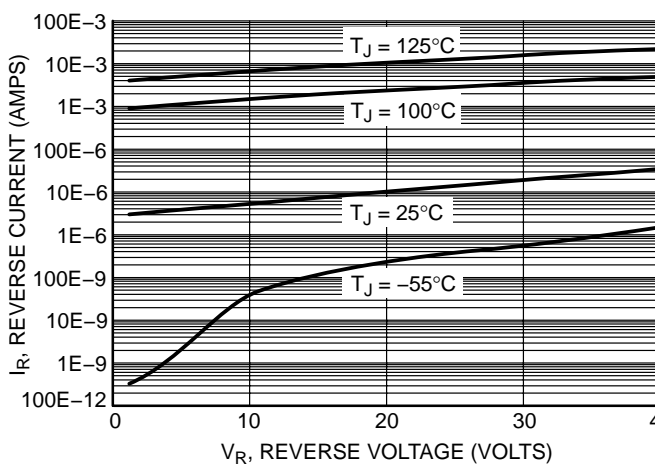


Figure 3. Typical Reverse Current

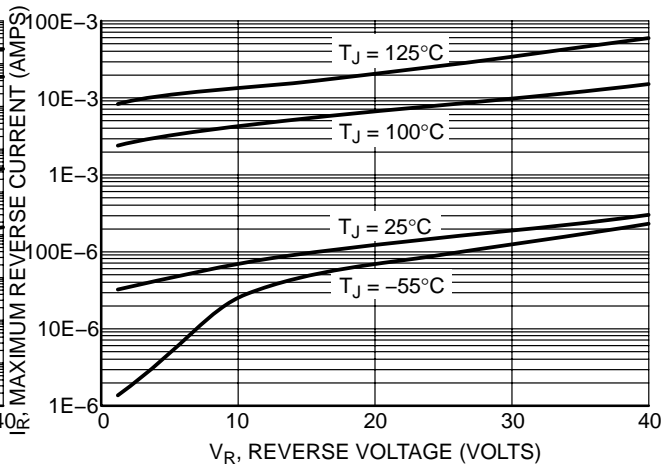


Figure 4. Maximum Reverse Current